



***SIGNATURES OF SPIN-ORBIT DRIVEN
ELECTRONIC TRANSPORT IN
TRANSITION- METAL-OXIDE INTERFACES***

Nicandro Bovenzi

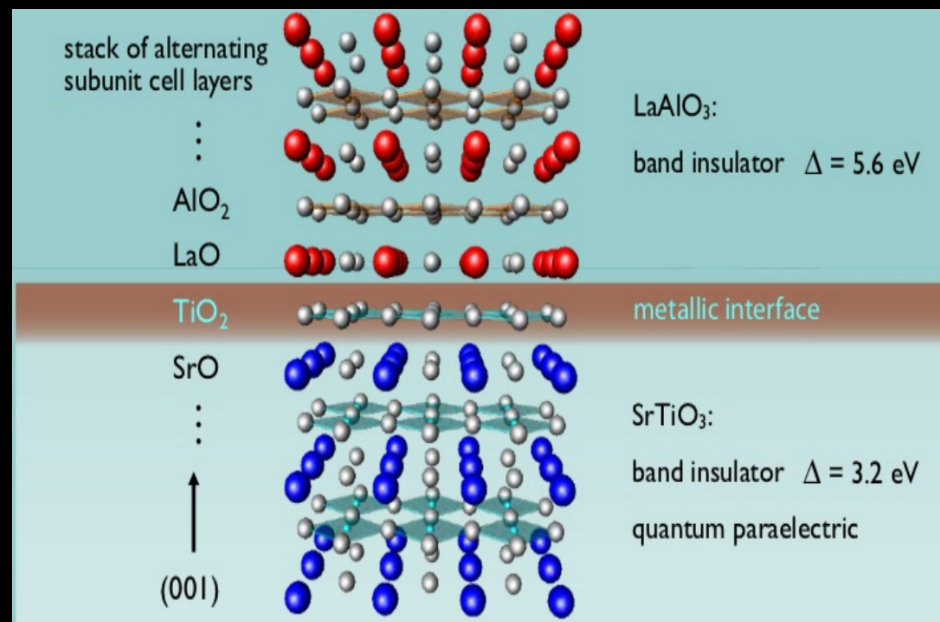
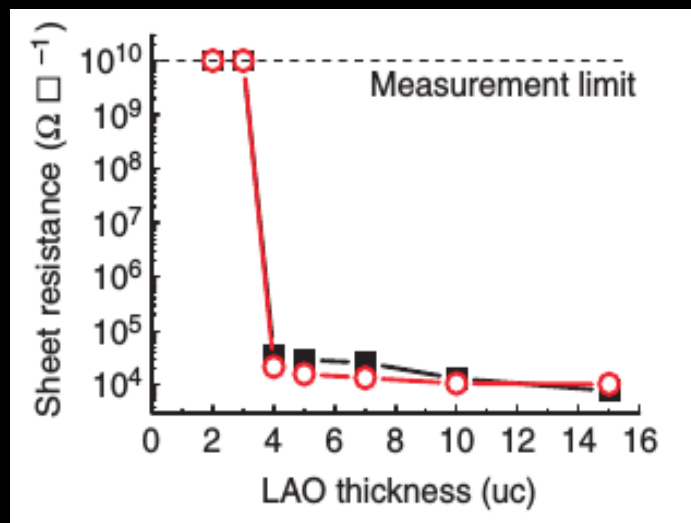
Bad Honnef, 19-22 September 2016

LAO/STO heterostructure:

conducting interface between two insulators

**conducting interface beyond
critical thickness of 3 unit cells**

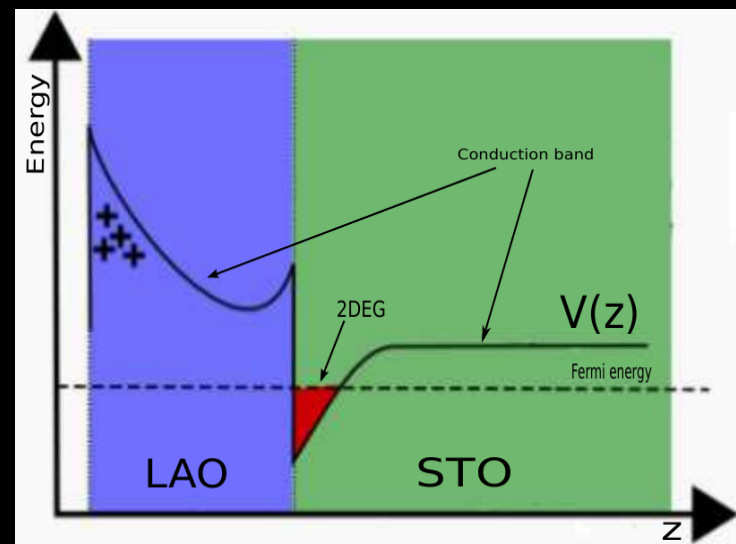
Ohtomo & Hwang Nature 427 (2004)



Surface reconstruction \rightarrow quantum-well confinement

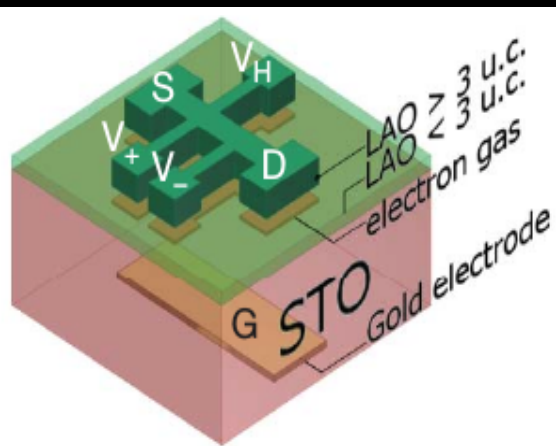
***z*-extension of the conducting region $\sim 2 - 10$ nm**

(lattice constant = 0.4 nm)



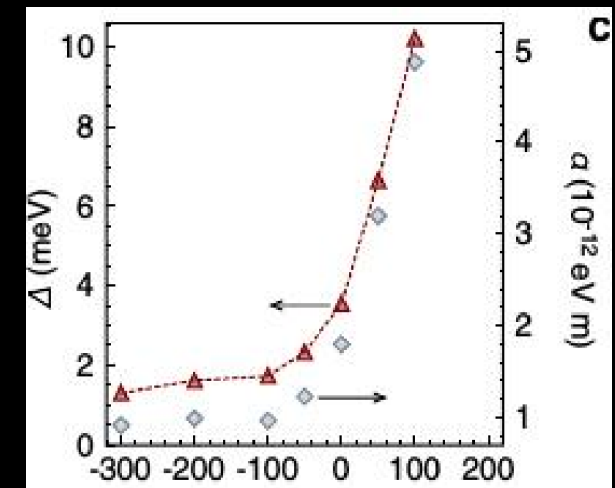
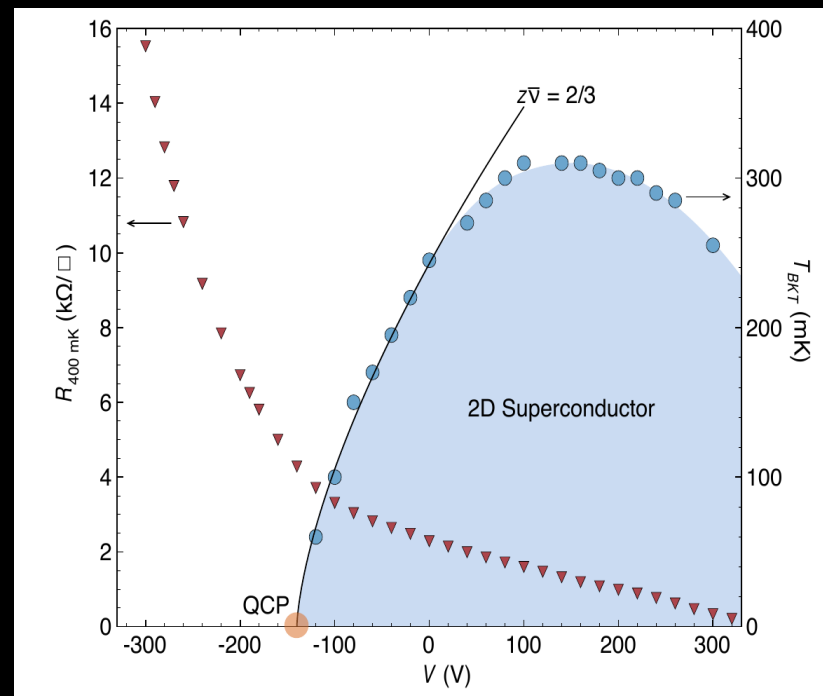
Electric-field control of the Ground State

Cavaglia *et al.*, Nature 456, 624-627 (2008)

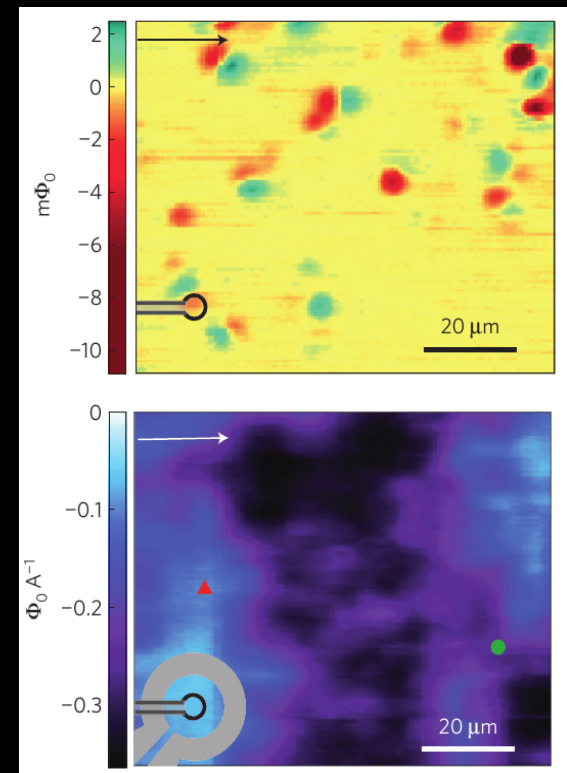


Bulk – insulating substrate with high dielectric constant ($10^3 - 10^4$ at low- T) allows large modulation of the carrier density at the interface via an applied gate - voltage

- Symmetry of the SC order parameter?
- Superconductivity vs. Spin-Orbit coupling (Top. SC?)



Cavaglia *et al.*, PRL 104, 126803 (2010)

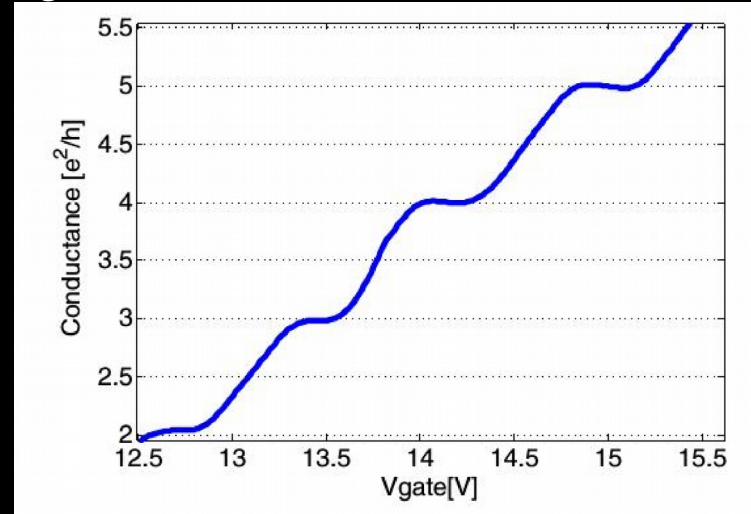
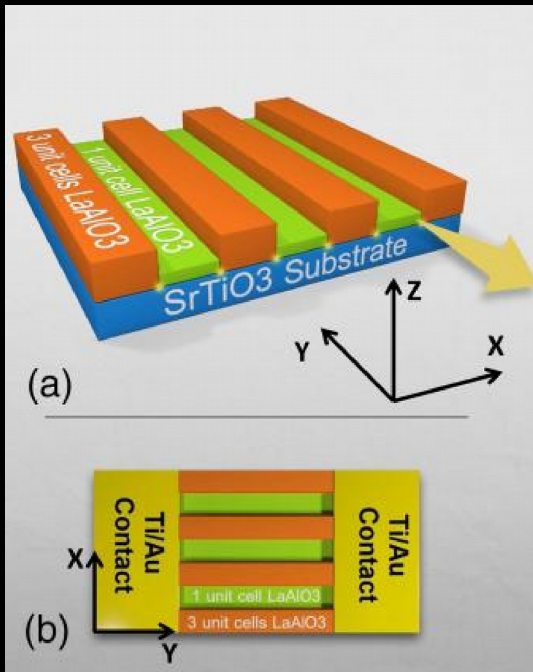


- Coexistence of magnetism and superconductivity? Bert *et al.*, Nat. Phys. (2011) Bert *et al.*, PRB (2012)
- Interactions between localized moments and conducting electrons (e.g. Kondo)? Joshua *et al.* PNAS (2013), Ruhman *et al.* PRB (2014)

Nanostructures

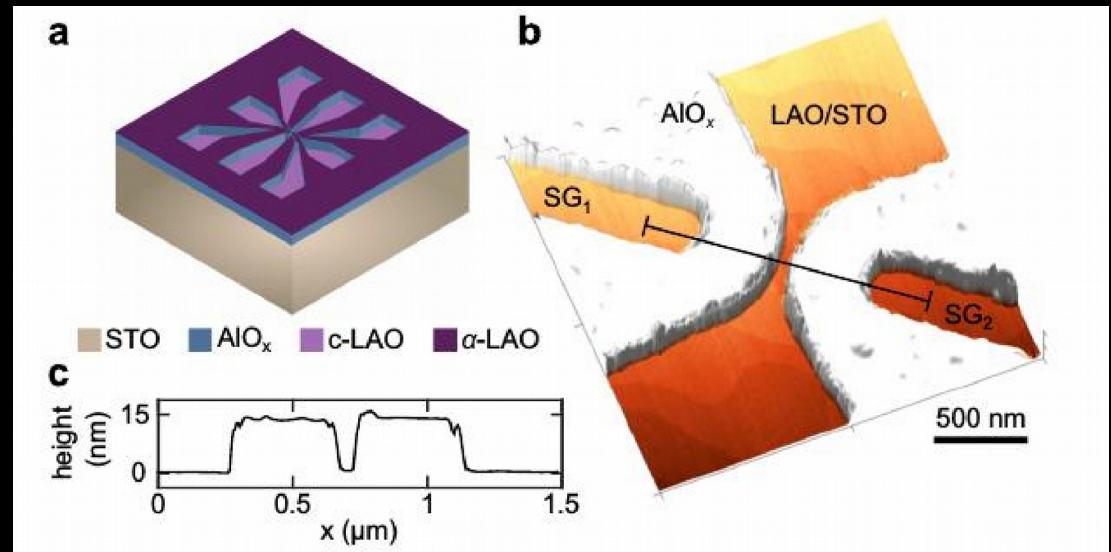
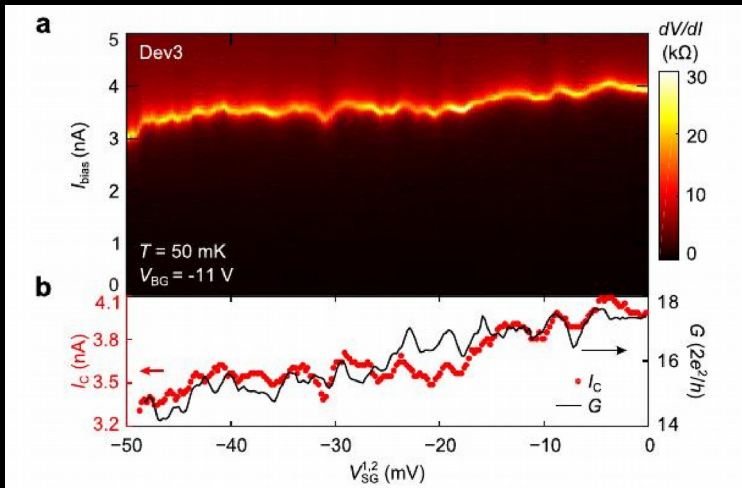
1D Quantum Wire with quantized conductance

Ron and Dagan, PRL 112, 136801 (2014)



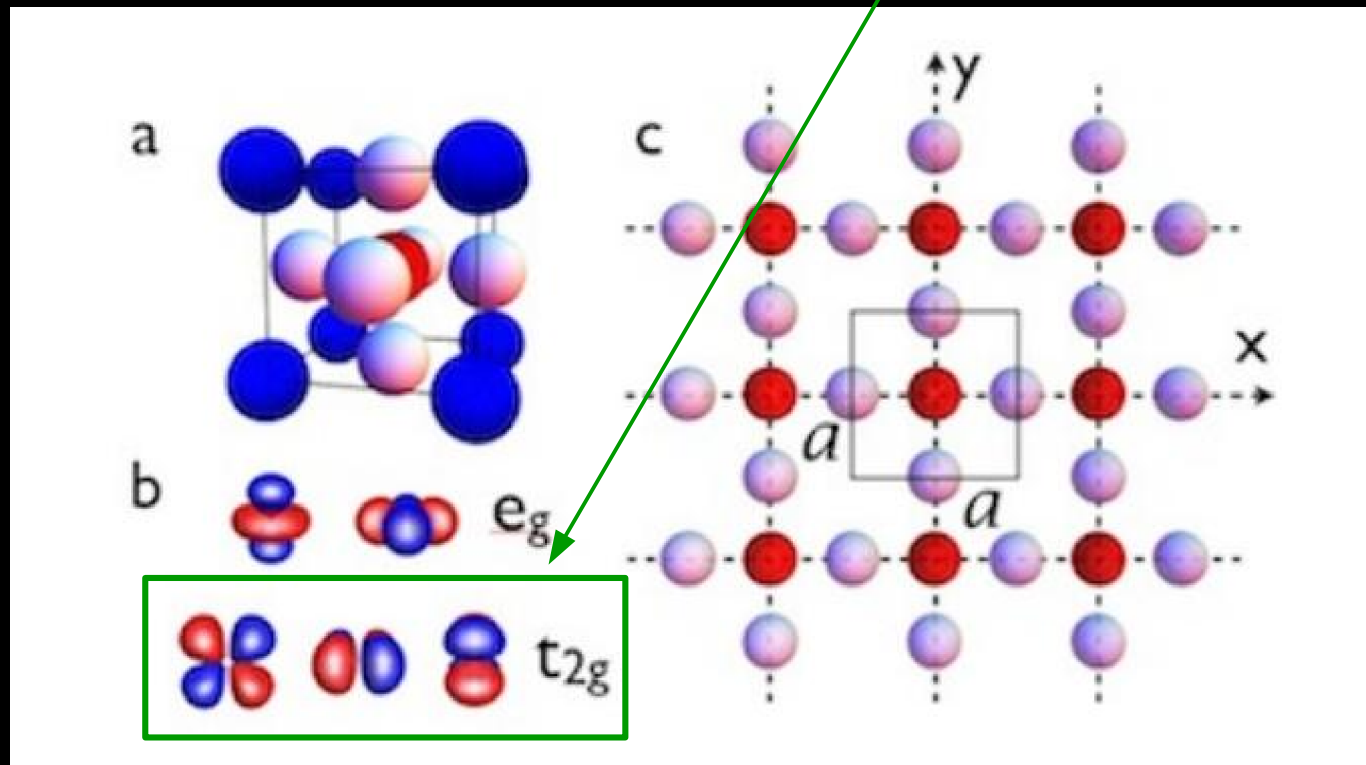
Side-gate tunable Josephson Junctions

A. Monteiro, D. Groenendijk, N. Manca, E. Mulazimoglu, S. Goswami, L. Vandersypen, A. Caviglia, arXiv:1609.03304



Electronic structure of the interface

Conduction bands derived from (d_{xy}, d_{xz}, d_{yz}) Ti-orbitals



“Sharp confinement” : Hamiltonian and band structure

Kinetic Hamiltonian

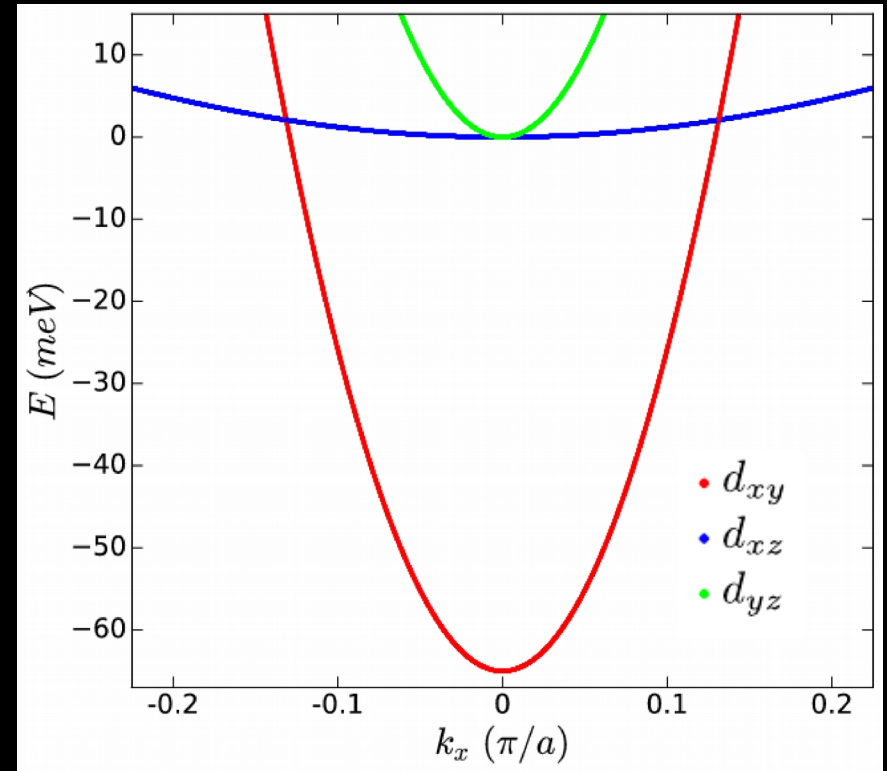
$$H_K = \begin{pmatrix} \epsilon_{xy}(k) - \Delta_E & 0 & 0 \\ 0 & \epsilon_{xz}(k) & \delta(k) \\ 0 & \delta(k) & \epsilon_{yz}(k) \end{pmatrix} \otimes \hat{\sigma}_0$$

$$\epsilon_{xy}(k) = 2t_l(2 - \cos k_x - \cos k_y)$$

$$\epsilon_{xz}(k) = 2t_l(1 - \cos k_x) + 2t_h(1 - \cos k_y)$$

$$\epsilon_{yz}(k) = 2t_h(1 - \cos k_x) + 2t_l(1 - \cos k_y)$$

$$\delta(k) = 2t_d \sin k_x \sin k_y$$



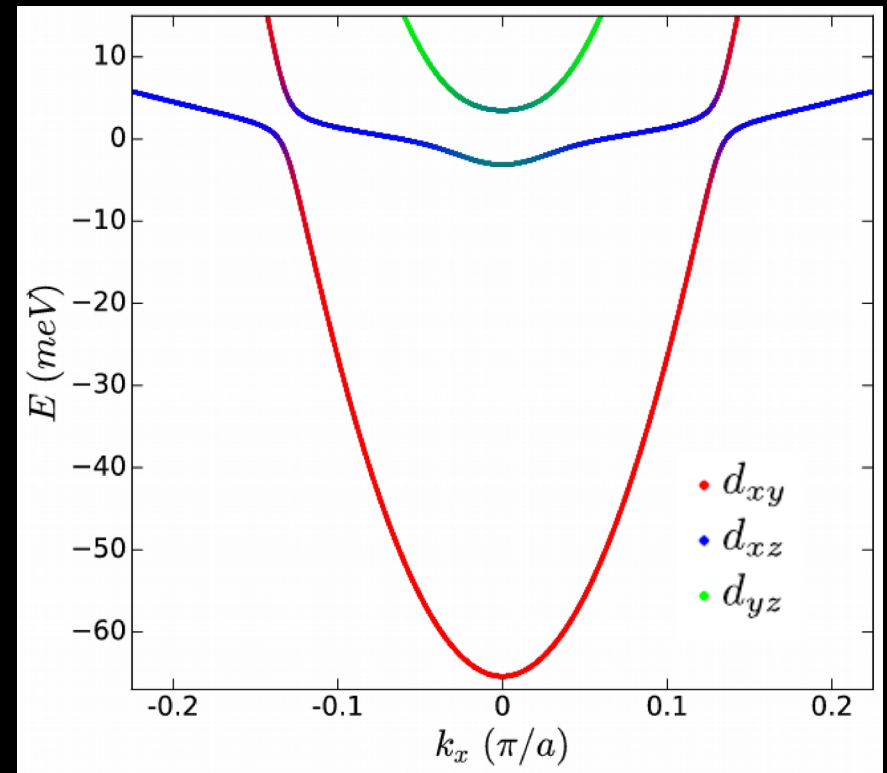
“Sharp confinement” : Hamiltonian and band structure

Kinetic Hamiltonian

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Atomic spin-orbit

$$H_{SO} = \frac{\Delta_{SO}}{2} \begin{pmatrix} 0 & i\hat{\sigma}_x & -i\hat{\sigma}_y \\ -i\hat{\sigma}_x & 0 & i\hat{\sigma}_z \\ i\hat{\sigma}_y & -i\hat{\sigma}_z & 0 \end{pmatrix}$$



“Sharp confinement” : Hamiltonian and band structure

Kinetic Hamiltonian

$$H_K = \begin{pmatrix} \epsilon_{xy}(k) - \Delta_E & 0 & 0 \\ 0 & \epsilon_{xz}(k) & \delta(k) \\ 0 & \delta(k) & \epsilon_{yz}(k) \end{pmatrix} \otimes \hat{\sigma}_0$$

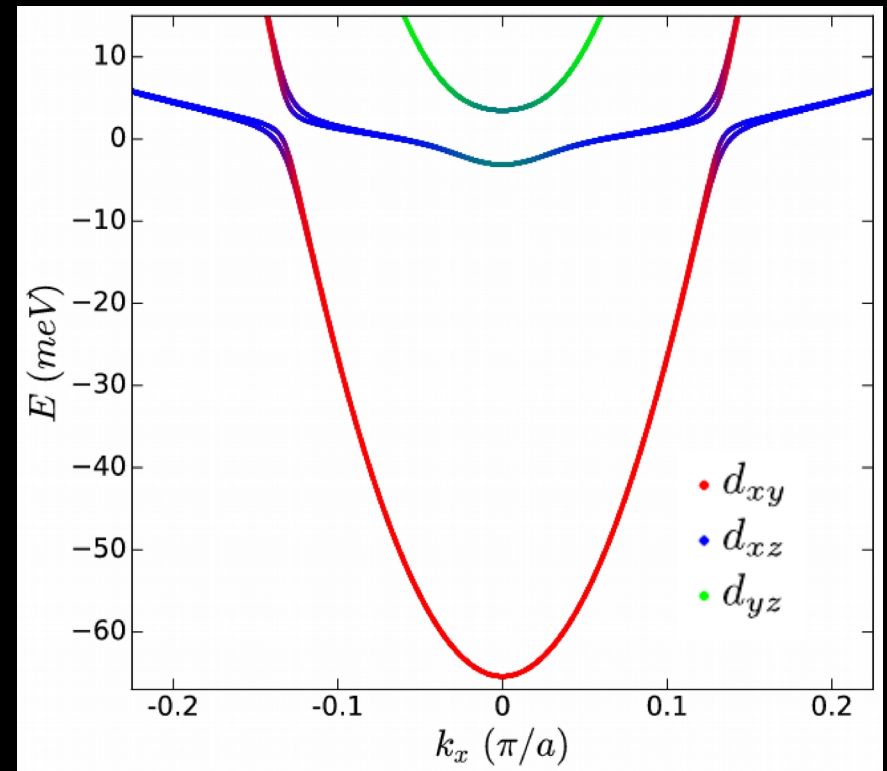
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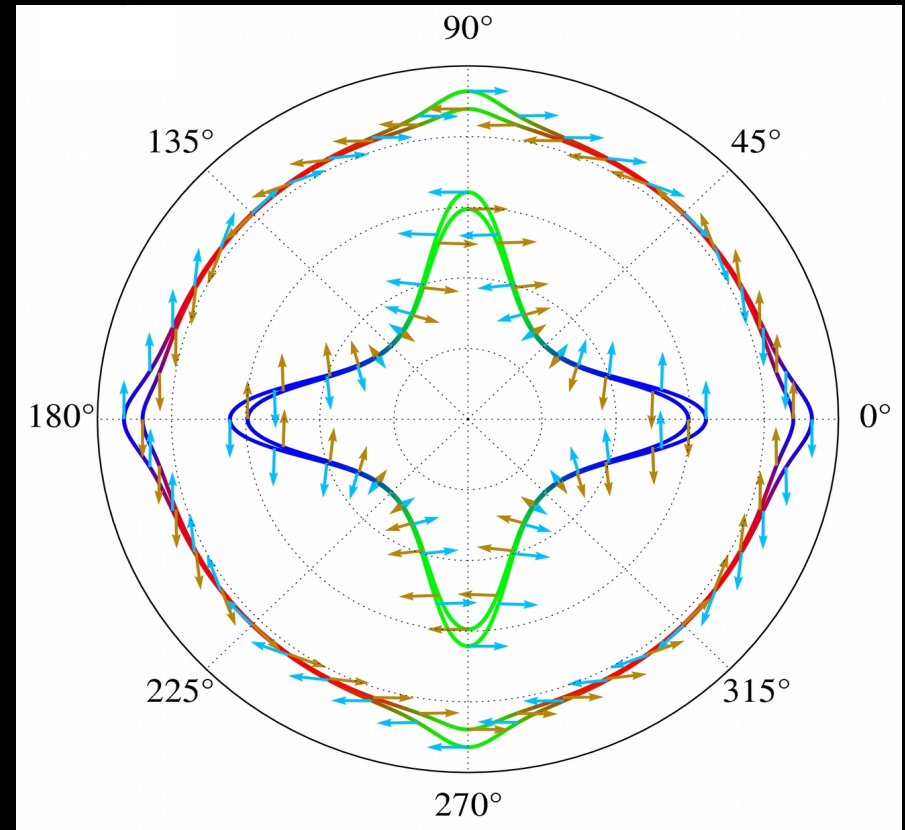
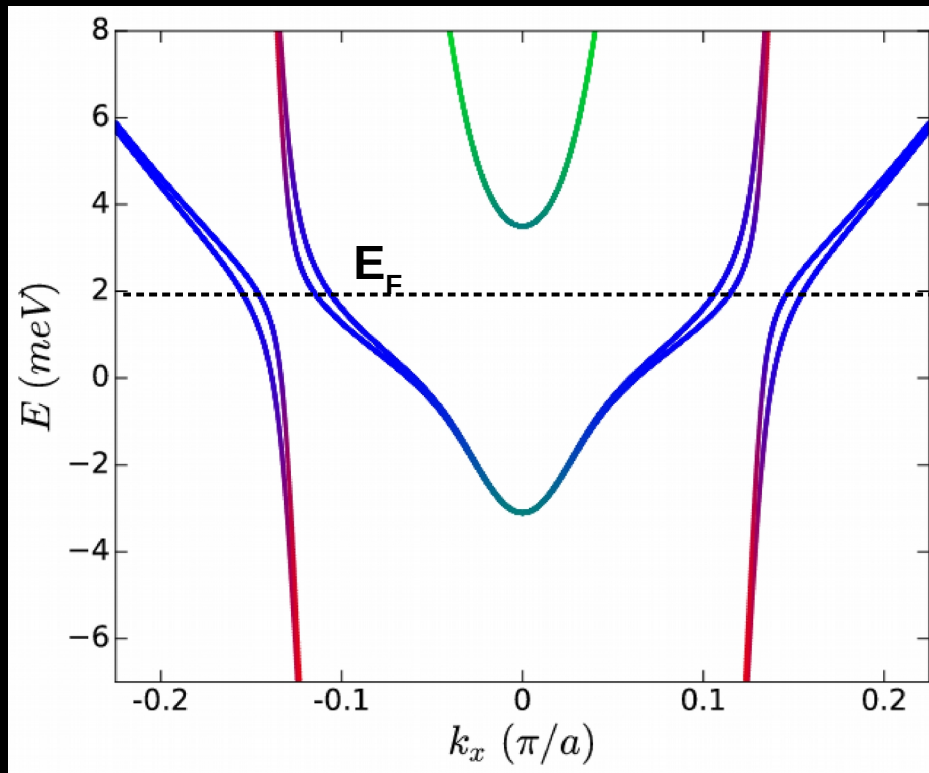
Inversion symmetry breaking

$$H_Z = \Delta_Z \begin{pmatrix} 0 & i \sin k_y & i \sin k_x \\ -i \sin k_y & 0 & 0 \\ -i \sin k_x & 0 & 0 \end{pmatrix} \otimes \hat{\sigma}_0$$

Khalsa, Lee and MacDonald, PRB 2013



Spin-orbit interaction gives band-mixing



- Electronic states with mixed orbital character at certain directions in the BZ
- In presence of scattering by disorder, transitions between different bands are allowed for any kind of potential (no need for “special” impurities)
- Spin-splitting not simply linear in k (unlike conventional Rashba-systems)
- maximally enhanced near the band (avoided) crossings

Boltzmann transport equation for scattering by impurities

$$f_{\mathbf{k},\nu} = f_0 + g_{\mathbf{k},\nu}$$

$$g_{\mathbf{k},\nu} = \Lambda_{\mathbf{k},\nu} \cdot \mathbf{E}$$

$$\Lambda_{\mathbf{k},\nu} \text{ Vector mean-free-path}$$

$$-e(\mathbf{v}_{\mathbf{k},\nu} \cdot \mathbf{E}) \partial f_0 / \partial \epsilon_{\mathbf{k},\nu} - (e/\hbar)(\mathbf{v}_{\mathbf{k},\nu} \times \mathbf{B}) \cdot \nabla_{\mathbf{k}} g_{\mathbf{k},\nu} =$$

Field-driven evolution

$$\sum_{\mathbf{k}',\nu'} Q_{\mathbf{k}\nu,\mathbf{k}'\nu'} (g_{\mathbf{k},\nu} - g_{\mathbf{k}',\nu'})$$

$$Q_{\mathbf{k}\nu,\mathbf{k}'\nu'} \sim e^{-\xi^2 |\mathbf{k}-\mathbf{k}'|^2/2} |\langle u_{\mathbf{k},\nu} | u_{\mathbf{k}',\nu'} \rangle|^2$$

momentum-dependent scattering amplitude
due to extended impurities

depends on the spin- and orbital-polarization of
the states

$$\Lambda = (\Lambda^x, \Lambda^y)$$

We solve the matrix equations

$$\Lambda^{x,y} = \mathcal{M} v^{x,y}$$

$$\Lambda^{x,y} = \begin{pmatrix} \Lambda_{i_1 n}^{x,y} \\ \Lambda_{i_2 n}^{x,y} \\ \cdot \\ \cdot \\ \cdot \\ \Lambda_{i_k m}^{x,y} \end{pmatrix}$$

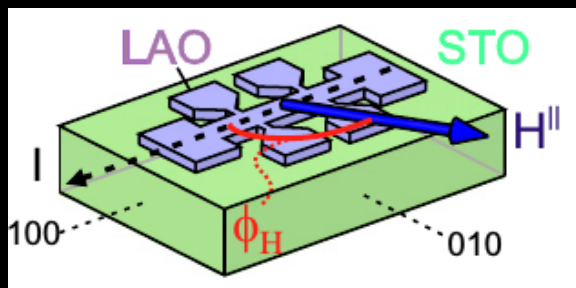
The two indices count respectively the number of discretized points on a single Fermi surface (i) and the number of bands (n)

$$\mathcal{M}_{in,jm} = -\frac{dl_{in}}{|\mathbf{v}_{in}|} q_{in,jm}$$

Scattering OUT

$$\mathcal{M}_{in,in} = \sum_{j,m} \frac{dl_{in}}{|\mathbf{v}_{in}|} q_{in,jm}$$

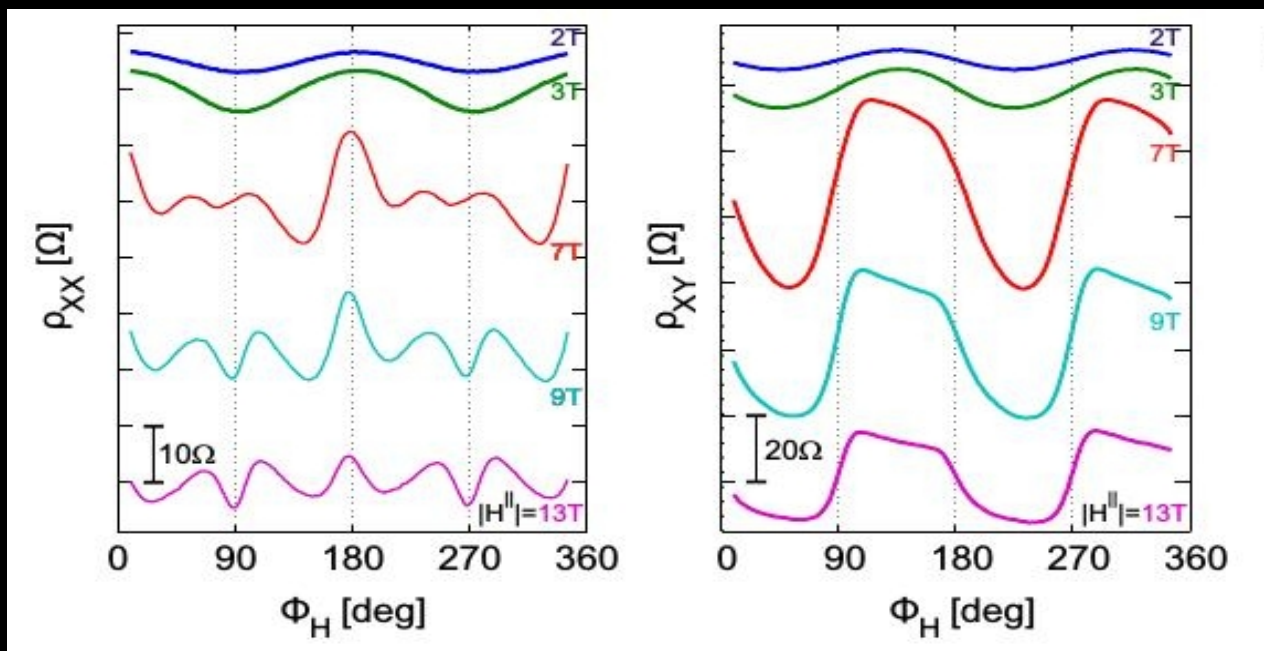
Scattering IN



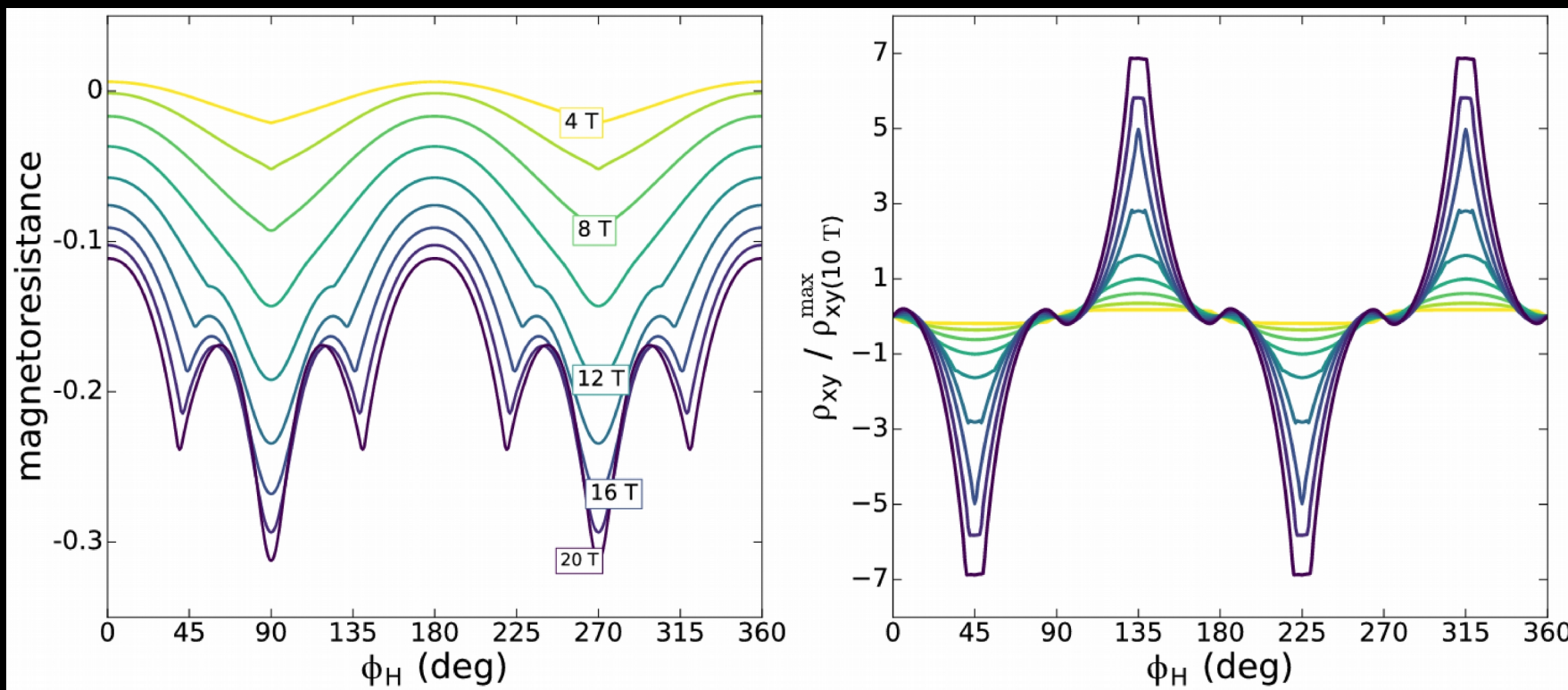
Joshua et al. PNAS 110, 9633 (2013)

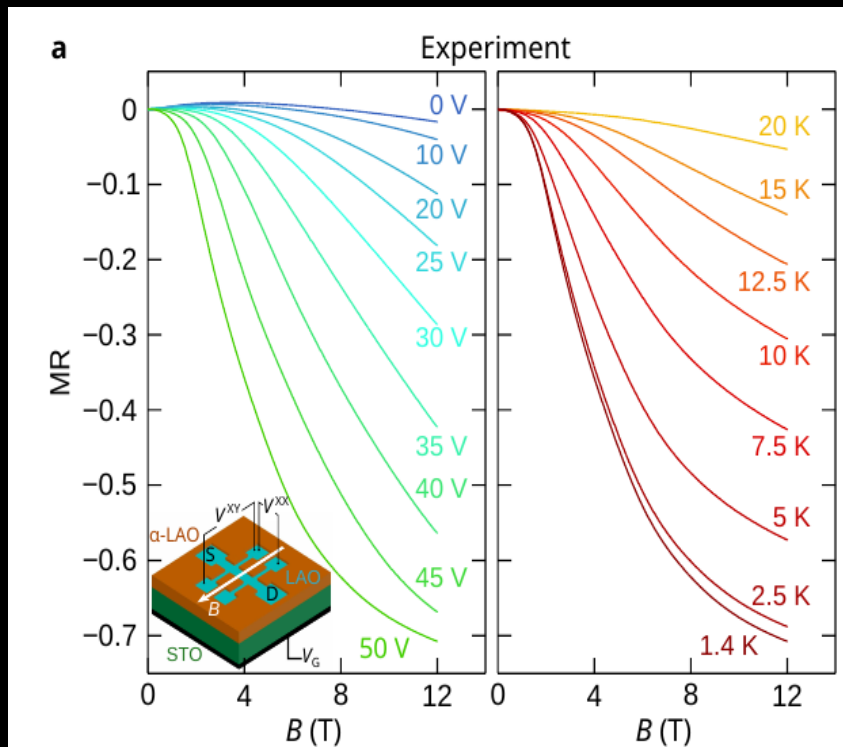
EXPERIMENTS show...

- very anisotropic negative MR
- large "Hall" resistivity with square-wave-like modulation



THEORY N. Bovenzi and M. Diez, arXiv:1609.00663



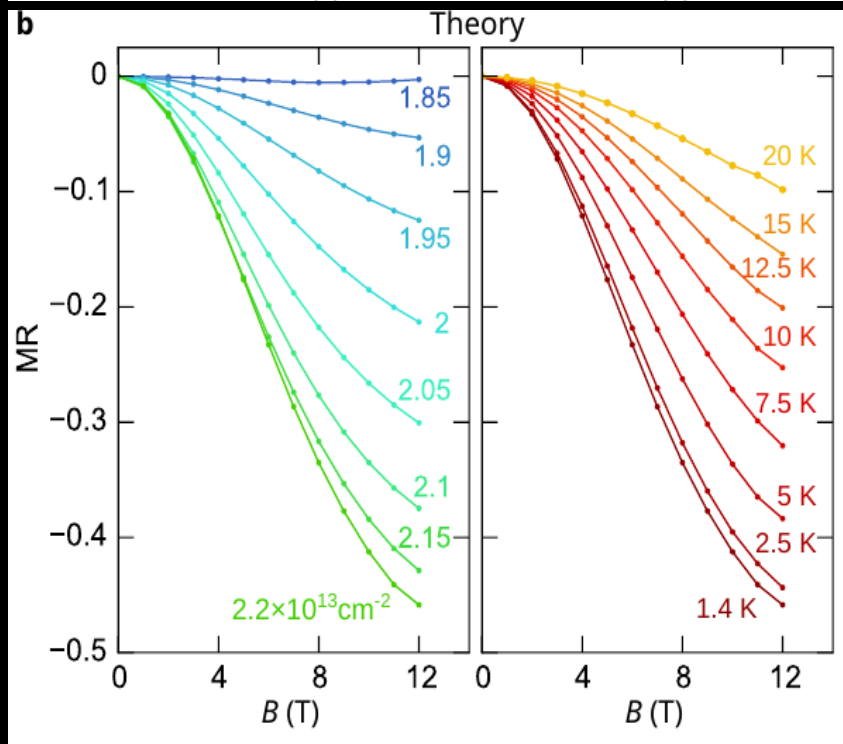


M. Diez, A. Monteiro, G. Mattoni, E. Cobanera, T. Hyart, E. Mulazimoglu, N. Bovenzi, C. Beenakker, A. Caviglia, PRL 115, 016803 (2015)

Curves at fixed (low) temperature as a function of the gate-voltage (density)

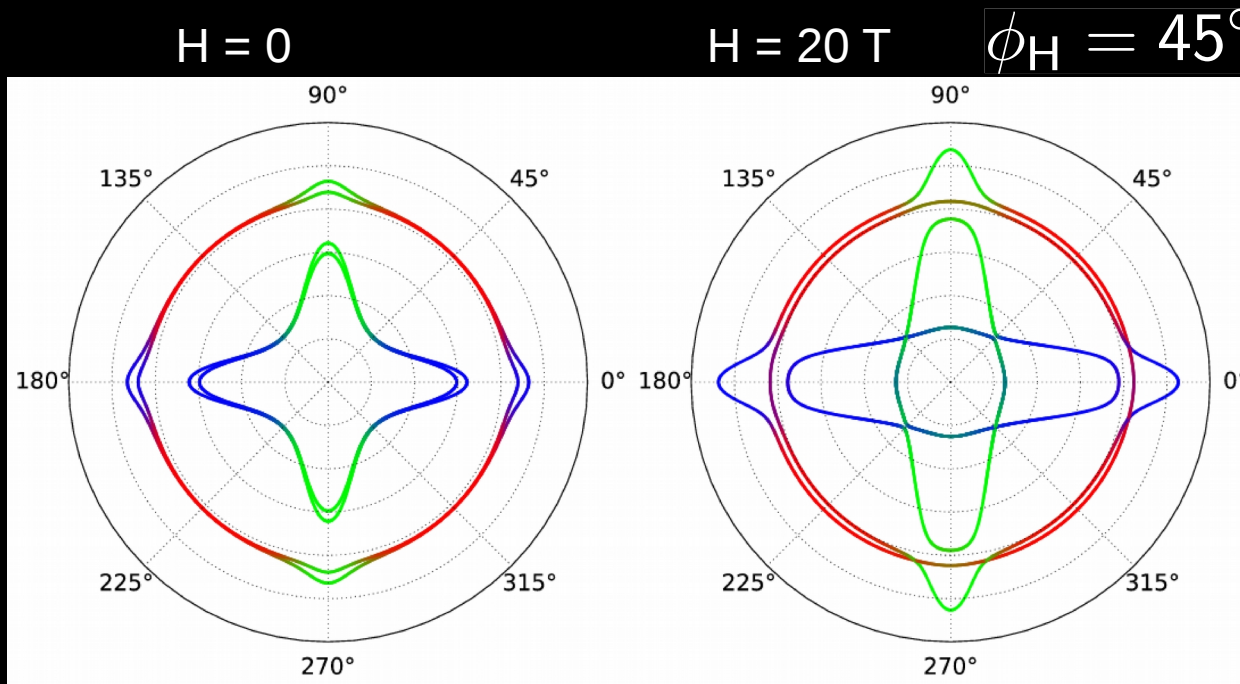
And

Curves at fixed (high) voltage as a function of temperature look similar

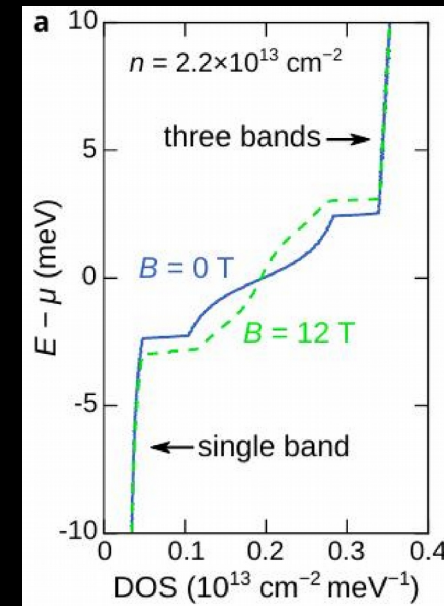


CLASSICAL EFFECTS:

- Suppression of *inter-band* scattering produces negative MR
- *Intra-band* scattering is anisotropically enhanced when the the magnetic field balances the spin-orbit field at points of maximal SO-hybridization (*effective Lorentz force*)



- Voltage/temperature symmetry of the curves naturally comes from downwards-renormalization of the chemical potential at finite T

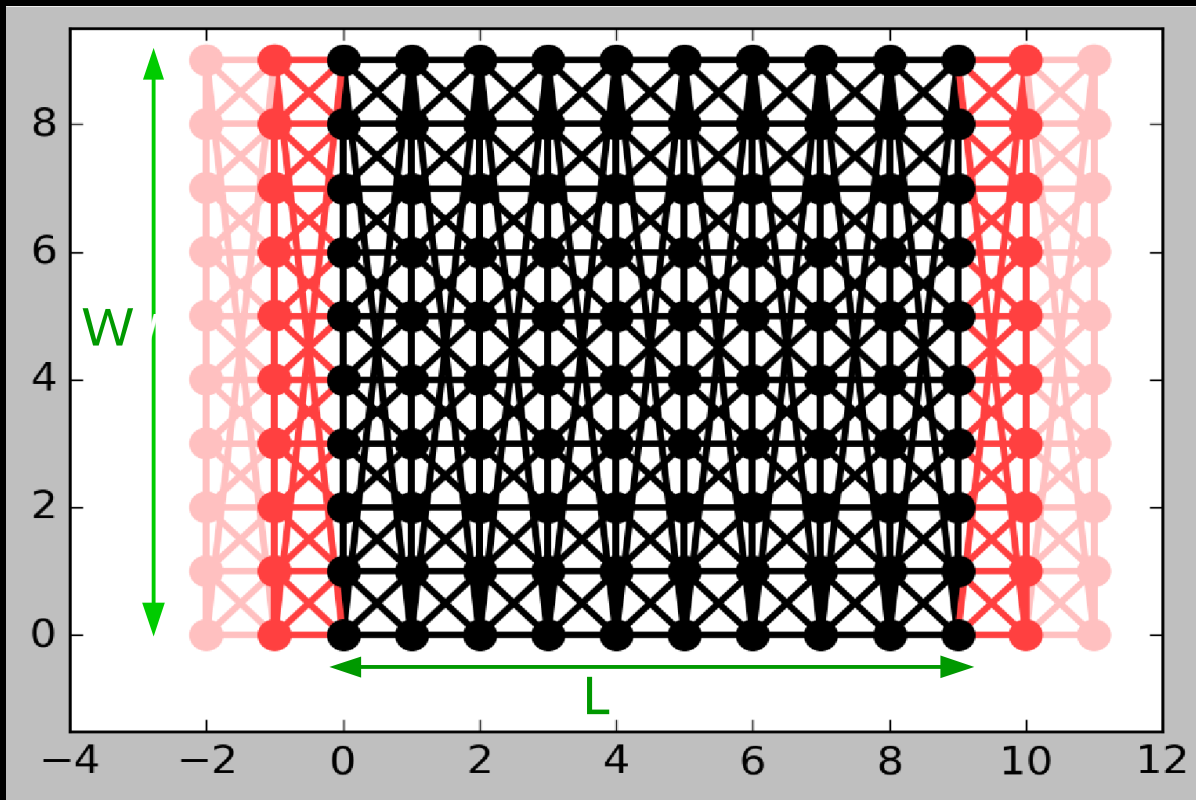


Current understanding and challenges...

- Spin-orbit coupling affects the band structure in a way that is not perturbatively treatable
- Orbital-mixing effects need to be properly modeled
- Implications for (diffusive) nanostructures (Thoulesse energy vs. spin-orbit energy)?
- What if the low-disorder approximation is not reliable?

Next future: Quantum Transport simulations

Kwant toolbox C. W. Groth, M. Wimmer, A. R. Akhmerov and X. Waintal, NJP 16, 063065 (2014)



$$\Psi_{out} = S \Psi_{in}$$

Scattering matrix

✓ Arbitrary disorder strength (not perturbative)

✗ No interactions

Landauer formula

$$G = \frac{e^2}{h} \text{Tr}(tt^\dagger)$$